Negative ion drift in a low pressure OTPC

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OUTLINE

- OTPC Detector Setup:
 - Triple-thin GEMs for ~100-150 Torr
 - Double-THGEMs and Glass GEMs for ~50 Torr
 - CCD and CMOS cameras
- Optimizing CF4/NI mixtures for an OTPC:
 - Measuring/minimizing diffusion
 - Measuring/maximizing light and light yield
- Results
 - Proton, alpha and nuclear recoil tracks at ~150 Torr
 - Low energy electron tracks at ~50 Torr

OTPC Detector

- 10 cm x 10 cm GEMs:
 - Standard thin GEMs
 - THGEMs ~ 0.45 mm pitch,
 0.4 mm thick
 - Glass-GEMs 280 um pitch, 570 um thick
- 1.5-2 cm drift
- 1D wire grid anode
- Optical readout:
 - CCD/CMOS cameras
 - 58 mm f/1.2 Nikon lens



Determine Optimal CF₄+NI Mixtures for NID

Doping CF₄ with small amount of NI gas and:

- 1. observe transition to negative ion drift (NID) in signal waveforms and alpha track images
- 2. quantify and optimize diffusion as a function of NI %:
 - Estimate σ_L using 60 cm drift TPC with charge readout
 - Estimate σ_{T} using width of Po-210 alpha tracks in optical readout
- 3. quantify effect of NI on light and light yield (LY):
 - Estimate light(charge) using optical(charge) Fe-55 spectrum
 - LY == light/charge using peaks in respective spectra

1. Transition to NID with increased NI content seen **qualitatively** in waveforms:



Small TPC with ~1.5 cm drift gap



...and also in images of Po-210 alpha tracks:



D. Loomba, UNM





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2a) Quantify diffusion (σ_L) and find optimal NI % using charge readout:



Results for σ_L in low pressure CF4/SF6 mixtures:



R. Lafler, PhD Thesis, UNM, 2019

2b) Quantify diffusion (σ_T) and find optimal NI % using alpha tracks in an OTPC:



The method

150 Torr CF₄





150 Torr CF₄ + 2.9 CS2





150 Torr CF₄ + 4.2 CS2





150 Torr CF₄ + 5.4 CS2





Results for σ_T :

150 Torr CF4 + x Torr CS2

CS ₂ (Torr)	σ(pix)	σ(μm)
0	9.21	~400
2.9	2.30	133.53
4.2	2.17	126.10
5.4	2.16	125.09

~45 Torr CF4 + x Torr CS2

CS ₂ (Torr)	σ(μm)
0	~550
4	~150-200

3. Fe-55 to quantify effect of NI on light and light yield (LY):





Light Yield (LY) in 150 Torr CF4 + x Torr CS2



Nuclear recoils in 150 Torr CF4 + 5 Torr CS2



What about low energy electrons and NRs?

- Need to go to lower pressures, ~50 Torr
- Higher signal-to-noise for low dE/dx particles
- > Double Glass-GEMs for high (>10⁵) gas gain at low P
 - 10 cm x 10 cm
 - 280 μm pitch, 570 μm thick
- Hamamatsu ORCA-Quest CMOS camera:



2. Realization of photon number resolving (PNR) output

Realization of photon number resolving by low-readout noise

Simulation data of photoelectron probability distribution (Average number of photoelectrons generated per pixel: 2 electrons)



* Photon number resolving is unique and quite different from photon counting (More precisely the method resolves the number of photoelectrons. However, since single photon counting instead of single photoelectron counting has been used for a comparable method in this field, we will use the term "photon number resolving" in this brochure).

Low light - Photon # Resolving



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More light



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Darks – 0.2s, ultra-quiet 1x1 binning, full chip



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Imaging low-energy Fe-55 electron tracks in a NI-OTPC

QUEST + G-GEMs: - 50 Torr CF4 - 45 Torr CF4 + 4.3 Torr CS₂

5.9 keV electron tracks in 50 Torr CF4





Fe-55 optical spectra and SNR:









Conclusions

- With with G-GEMs and Quest camera high SNR we have shown at a negative ion OTPC can image particle tracks with the very high resolution
- This enables:
 - detailed reconstruction of the particle's trajectory
 - mapping of the ionization loss
 - particle ID, from NRs to low energy electrons
 - reconstructing the interaction vertex and initial direction
 - etc
- Applications include
 - directional DM and v searches (CYGNO, CYGNUS)
 - Migdal effect (MIGDAL)
 - X-ray polarimetry
 - rare nuclear decays, and many others





BACKUP SLIDES

Specification

Product number		C15550-20UP
Imaging device		qCMOS [®] image sensor
Effective number of pixels		4096 (H) × 2304 (V)
Pixel size		4.6 μm (H) × 4.6 μm (V)
Effective area		18.841 mm (H) × 10.598 mm (V)
Quantum efficiency (typ.)		90 % (peak QE)
Full well capacity (typ.)		7000 electrons
Readout noise (typ.)	Standard scan	0.43 electrons rms
	Ultra quiet scan	0.27 electrons rms
Dynamic range (typ.) *1		25 900: 1
Dark signal non-uniformity (DSNU) (typ.) *2		0.06 electrons rms
Photoresponse non-uniformity (PRNU) (typ.) *2*3		0.1 % rms
Linearity error	EMVA 1288 standard (typ.)	0.5 %

Cooling	Sensor temperature	Dark current (typ.)
Forced-air cooled (Ambient temperature: +25 °C)	-20 °C	0.016 electrons/pixels/s
Water cooled (Water temperature: +25 °C)	-20 °C	0.016 electrons/pixels/s
Water cooled (max cooling) (typ.) *4	−35 °C	0.006 electrons/pixels/s

Four key features that enable the ORCA®-Quest to achieve ultimate quantitative imaging

Ultra-low readout noise 0.27 electrons rms at Ultra quiet scan

In order to detect weak light with high signal-to-noise, ORCA®-Quest has been designed and optimized to evstructure to its electronics. Not only the camera development but also the custom sensor development has technology, an extremely low noise performance of 0.27 electrons has been achieved.



Low-dark current 0.006 electrons/pixel/s at -35 °C

In the field of single photon counting and photon number resolving, even dark currents as low as 0.5 electrons/pixel/s can affect photon detection. The 0.006 electrons/pixel/s @-35 °C value achieved by ORCA[®]-Quest is an extremely low probabilistic value of only 1 electron of dark current generated in approximately 167 pixels when exposed for 1 second.

Thus, the ORCA®-Quest, which is less affected by dark current, is ideal for quantitative imaging and analysis.

ORCA®-Quest

1.



Gen II sCMOS camera



Image quality comparison at long exposure time (pseudo-color) Incident light Intensity: 0.05 photons/pixel/s Exposure time: 15 min (10 s × 90 times Integration)

2. Realization of photon number resolving (PNR) output

Realization of photon number resolving by low-readout noise

Simulation data of photoelectron probability distribution (Average number of photoelectrons generated per pixel: 2 electrons)



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3. Back-illuminated structure and high resolution

Trench structure to suppress crosstalk

High QE is essential for high efficiency of detecting photons and achieved by back-illuminated structure.

High QE 90 % at 475 nm 33 % at 900 nm

It also has high quantum efficiency in the near-infrared region because of its thicker layer of the charge detection region.

Normally, there is a trade-off between the thickness of the layer of the photon detection region and the resolution, but the trench structure suppresses the degradation of the resolution.



4. Realization of a large number of pixels and high speed readout

Realization of PC/PNR with a large number of pixels and high speed at Ultra quiet scan

Photon counting (PC) level images have typically been acquired using electron multiplication camera such as EM-CCD camera with about 0.3 megapixels. However, ORCA®-Quest can acquire not only PC level images but also photon number resolving images with 9.4 megapixels.

In addition, it is not fair to compare readout speeds of cameras with different pixel number by frame rate. In such a case the pixel rate (number of pixels X frame rate), which is the number of pixels read out per second, is used.

Until now, the fastest camera capable of SPC readout was the EM-CCD camera with about 27 megapixel/s, but the ORCA®-Quest enables photon number resolving imaging at about 47 megapixel/s, nearly twice as fast.

ORCA®-Quest (4096 × 2304)





EM-CCD camera (1024 × 1024)



Excellent pixel count and readout speed at Standard scan

ORCA[®]-Quest delivers low noise and it has 4096 (H) × 2304 (V) pixels, about 2.2 times larger than a conventional Gen II sCMOS camera, allowing for the simultaneous capture of a large number of objects. Standard scan delivers less readout noise (0.43 electron), and 2.8 times faster speed than a conventional Gen II sCMOS camera, which enables high-speed low light imaging.



Sensor sizes that can be used with general-purpose optical systems

As the number of pixels increases, the size of the sensor also increases, resulting in cases where the peripheral field of view is missing when using optics such as under a microscope. The ORCA⁶-Quest has 18.841 mm (H) × 10.598 mm (V) by 9.4 megapixels, 4.6 µm px size, that fits in a C-mount of dia.25.4 mm, making it suitable for use with general-purpose optics.

* An F-mount option is also available.



More Noise – standard scan



Darks – 0.2s, ultra-quiet 1x1 binning, full chip (~9.4 Mpix)



Why not Gaussian?

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Distribution of Darks for a sample of pixels



Focus



Focus





Focus

